

BC817; BC817W; BC337

45 V, 500 mA NPN general-purpose transistors

Rev. 05 — 21 January 2005

Product data sheet

1. Product profile

1.1 General description

NPN general-purpose transistors.

Table 1: Product overview

| Type number | Package | | PNP complement |
|-------------|---------------|--------|----------------|
| | Philips | JEITA | |
| BC817 | SOT23 | - | BC807 |
| BC817W | SOT323 | SC-70 | BC807W |
| BC337 [1] | SOT54 (TO-92) | SC-43A | BC327 |

[1] Also available in SOT54A and SOT54 variant packages (see [Section 2](#)).

1.2 Features

- High current
- Low voltage

1.3 Applications

- General-purpose switching and amplification

1.4 Quick reference data

Table 2: Quick reference data

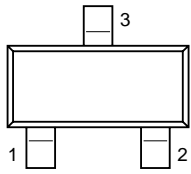
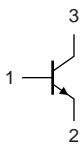
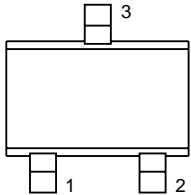
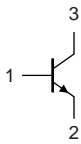
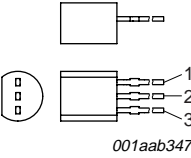
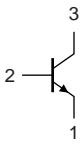
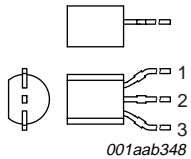
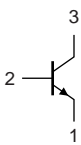
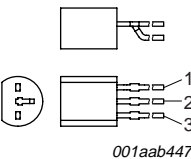
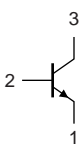
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------|-------------------------------|---|-----|-----|-----|------|
| V_{CEO} | collector-emitter voltage | open base; $I_C = 10 \text{ mA}$ | - | - | 45 | V |
| I_C | collector current (DC) | | - | - | 500 | mA |
| I_{CM} | peak collector current | | - | - | 1 | A |
| h_{FE} | DC current gain | $I_C = 100 \text{ mA};$ $V_{CE} = 1 \text{ V}$ | [1] | - | - | - |
| | BC817; BC817W; BC337 | | | 100 | - | 600 |
| | BC817-16; BC817-16W; BC337-16 | | | 100 | - | 250 |
| | BC817-25; BC817-25W; BC337-25 | | | 160 | - | 400 |
| | BC817-40; BC817-40W; BC337-40 | | | 250 | - | 600 |

[1] Pulse test: $t_p \leq 300 \mu\text{s}$; $\delta \leq 0.02$.

PHILIPS

2. Pinning information

Table 3: Pinning

| Pin | Description | Simplified outline | Symbol |
|----------------------|-------------|--|---|
| SOT23 | | | |
| 1 | base |  <p>SOT23</p> |  <p>sym021</p> |
| 2 | emitter | | |
| 3 | collector | | |
| SOT323 | | | |
| 1 | base |  <p>sot323_so</p> |  <p>sym021</p> |
| 2 | emitter | | |
| 3 | collector | | |
| SOT54 | | | |
| 1 | emitter |  <p>001aab347</p> |  <p>sym026</p> |
| 2 | base | | |
| 3 | collector | | |
| SOT54A | | | |
| 1 | emitter |  <p>001aab348</p> |  <p>sym026</p> |
| 2 | base | | |
| 3 | collector | | |
| SOT54 variant | | | |
| 1 | emitter |  <p>001aab447</p> |  <p>sym026</p> |
| 2 | base | | |
| 3 | collector | | |

3. Ordering information

Table 4: Ordering information

| Type number ^[1] | Package | | |
|----------------------------|---------|---|---------|
| | Name | Description | Version |
| BC817 | - | plastic surface mounted package; 3 leads | SOT23 |
| BC817W | SC-70 | plastic surface mounted package; 3 leads | SOT323 |
| BC337 ^[2] | SC-43A | plastic single-ended leaded (through hole) package; 3 leads | SOT54 |

[1] Valid for all available selection groups.

[2] Also available in SOT54A and SOT54 variant packages (see [Section 2](#) and [Section 9](#)).

4. Marking

Table 5: Marking codes

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| BC817 | 6D* |
| BC817-16 | 6A* |
| BC817-25 | 6B* |
| BC817-40 | 6C* |
| BC817W | 6D* |
| BC817-16W | 6A* |
| BC817-25W | 6B* |
| BC817-40W | 6C* |
| BC337 | C337 |
| BC337-16 | C33716 |
| BC337-25 | C33725 |
| BC337-40 | C33740 |

[1] * = -: made in Hong Kong
 * = p: made in Hong Kong
 * = t: made in Malaysia
 * = W: made in China

5. Limiting values

Table 6: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit | |
|-----------|---------------------------|-----------------------------|--------|------|------|----|
| V_{CBO} | collector-base voltage | open emitter | - | 50 | V | |
| V_{CEO} | collector-emitter voltage | open base; $I_C = 10$ mA | - | 45 | V | |
| V_{EBO} | emitter-base voltage | open collector | - | 5 | V | |
| I_C | collector current (DC) | | - | 500 | mA | |
| I_{CM} | peak collector current | | - | 1 | A | |
| I_{BM} | peak base current | | - | 200 | mA | |
| P_{tot} | total power dissipation | | | | | |
| | BC817 | $T_{amb} \leq 25$ °C | [1][2] | - | 250 | mW |
| | BC817W | $T_{amb} \leq 25$ °C | [1][2] | - | 200 | mW |
| | BC337 | $T_{amb} \leq 25$ °C | [1][2] | - | 625 | mW |
| T_{stg} | storage temperature | | -65 | +150 | °C | |
| T_j | junction temperature | | - | 150 | °C | |
| T_{amb} | ambient temperature | | -65 | +150 | °C | |

[1] Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

[2] Valid for all available selection groups.

6. Thermal characteristics

Table 7: Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|---------------|---|----------------------|--------|-----|-----|------|-----|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | | | | | | |
| | BC817 | $T_{amb} \leq 25$ °C | [1][2] | - | - | 500 | K/W |
| | BC817W | $T_{amb} \leq 25$ °C | [1][2] | - | - | 625 | K/W |
| | BC337 | $T_{amb} \leq 25$ °C | [1][2] | - | - | 200 | K/W |

[1] Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

[2] Valid for all available selection groups.

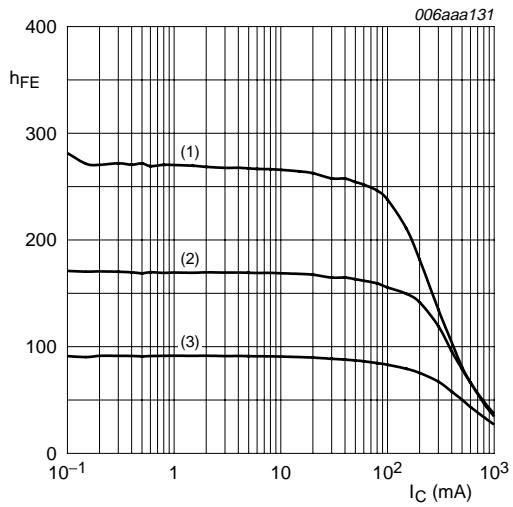
7. Characteristics

Table 8: Characteristics
 $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------|--------------------------------------|---|--------|-----|-----|---------------|
| I_{CBO} | collector-base cut-off current | $I_E = 0\text{ A}; V_{CB} = 20\text{ V}$ | - | - | 100 | nA |
| | | $I_E = 0\text{ A}; V_{CB} = 20\text{ V}; T_j = 150\text{ }^{\circ}\text{C}$ | - | - | 5 | μA |
| I_{EBO} | emitter-base cut-off current | $I_C = 0\text{ A}; V_{EB} = 5\text{ V}$ | - | - | 100 | nA |
| h_{FE} | DC current gain | $I_C = 100\text{ mA}; V_{CE} = 1\text{ V}$ | [1] | | | |
| | | BC817; BC817W; BC337 | 100 | - | 600 | |
| | | BC817-16; BC817-16W; BC337-16 | 100 | - | 250 | |
| | | BC817-25; BC817-25W; BC337-25 | 160 | - | 400 | |
| | BC817-40; BC817-40W; BC337-40 | 250 | - | 600 | | |
| h_{FE} | DC current gain | $I_C = 500\text{ mA}; V_{CE} = 1\text{ V}$ | [1] 40 | - | - | |
| V_{CEsat} | collector-emitter saturation voltage | $I_C = 500\text{ mA}; I_B = 50\text{ mA}$ | [1] - | - | 700 | mV |
| V_{BE} | base-emitter voltage | $I_C = 500\text{ mA}; V_{CE} = 1\text{ V}$ | [2] - | - | 1.2 | V |
| C_c | collector capacitance | $I_E = i_e = 0\text{ A}; V_{CB} = 10\text{ V}; f = 1\text{ MHz}$ | - | 3 | - | pF |
| f_T | transition frequency | $I_C = 10\text{ mA}; V_{CE} = 5\text{ V}; f = 100\text{ MHz}$ | 100 | - | - | MHz |

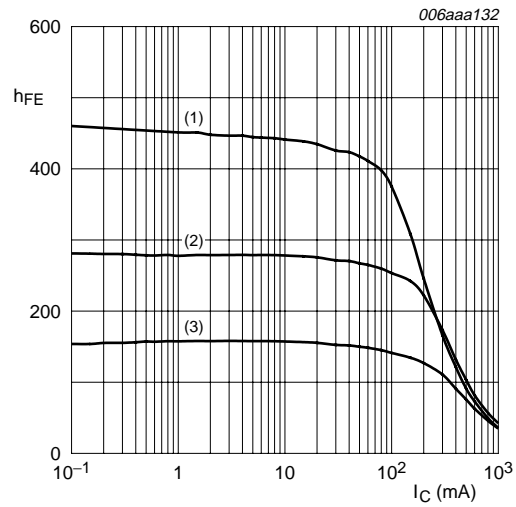
[1] Pulse test: $t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02$.

[2] V_{BE} decreases by approximately 2 mV/K with increasing temperature.



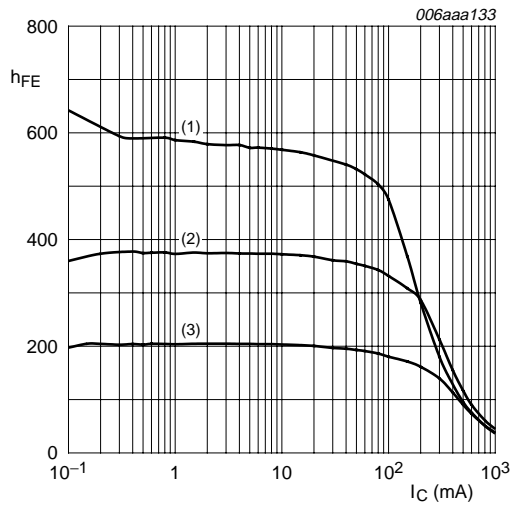
$V_{CE} = 1 \text{ V.}$
 (1) $T_{amb} = 150 \text{ }^\circ\text{C.}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C.}$
 (3) $T_{amb} = -55 \text{ }^\circ\text{C.}$

Fig 1. Selection -16: DC current gain as a function of collector current; typical values.



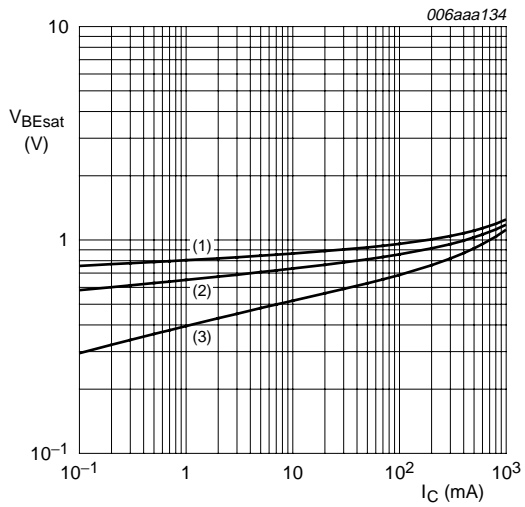
$V_{CE} = 1 \text{ V.}$
 (1) $T_{amb} = 150 \text{ }^\circ\text{C.}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C.}$
 (3) $T_{amb} = -55 \text{ }^\circ\text{C.}$

Fig 2. Selection -25: DC current gain as a function of collector current; typical values.



$V_{CE} = 1 \text{ V.}$
 (1) $T_{amb} = 150 \text{ }^\circ\text{C.}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C.}$
 (3) $T_{amb} = -55 \text{ }^\circ\text{C.}$

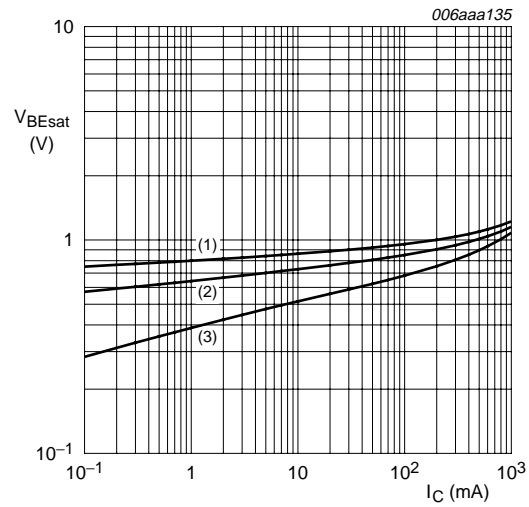
Fig 3. Selection -40: DC current gain as a function of collector current; typical values.



$I_C/I_B = 10$.

- (1) $T_{amb} = -55\text{ °C}$.
- (2) $T_{amb} = 25\text{ °C}$.
- (3) $T_{amb} = 150\text{ °C}$.

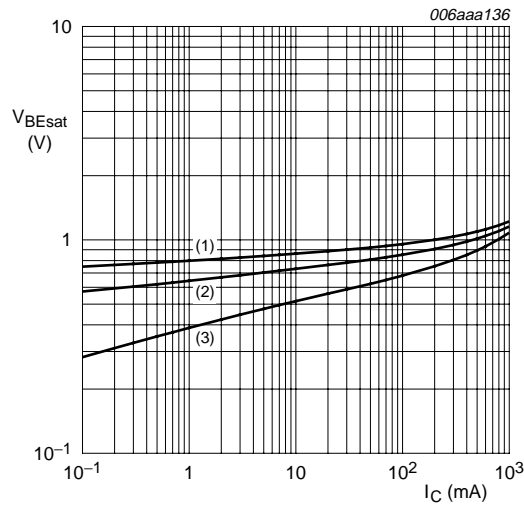
Fig 4. Selection -16: Base-emitter saturation voltage as a function of collector current; typical values.



$I_C/I_B = 10$.

- (1) $T_{amb} = -55\text{ °C}$.
- (2) $T_{amb} = 25\text{ °C}$.
- (3) $T_{amb} = 150\text{ °C}$.

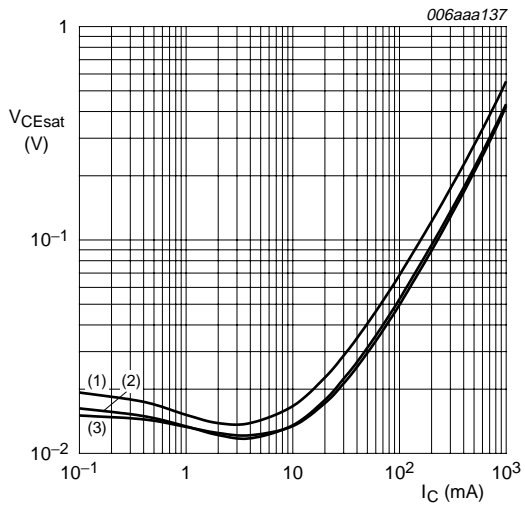
Fig 5. Selection -25: Base-emitter saturation voltage as a function of collector current; typical values.



$I_C/I_B = 10$.

- (1) $T_{amb} = -55\text{ °C}$.
- (2) $T_{amb} = 25\text{ °C}$.
- (3) $T_{amb} = 150\text{ °C}$.

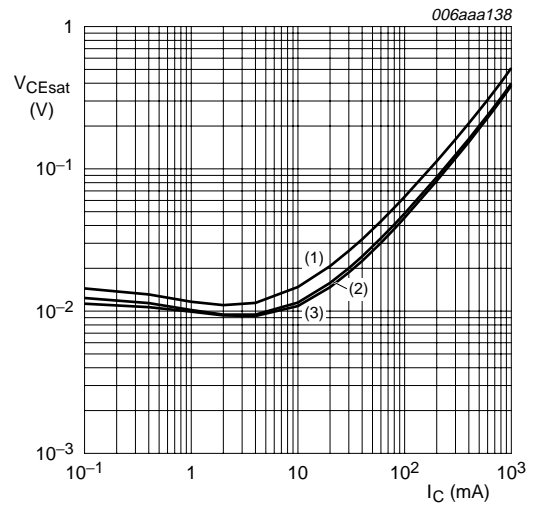
Fig 6. Selection -40: Base-emitter saturation voltage as a function of collector current; typical values.



$I_C/I_B = 10$.

- (1) $T_{amb} = 150\text{ °C}$.
- (2) $T_{amb} = 25\text{ °C}$.
- (3) $T_{amb} = -55\text{ °C}$.

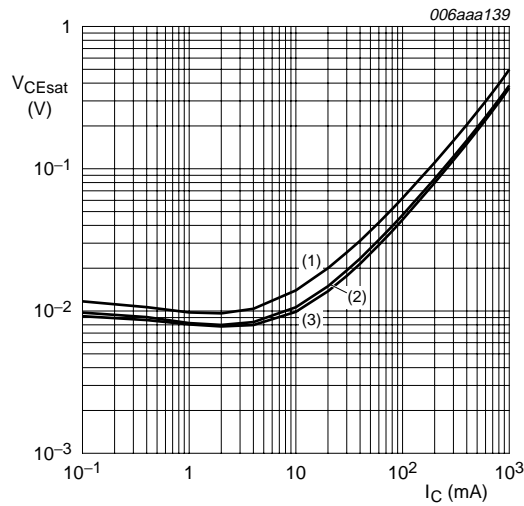
Fig 7. Selection -16: Collector-emitter saturation voltage as a function of collector current; typical values.



$I_C/I_B = 10$.

- (1) $T_{amb} = 150\text{ °C}$.
- (2) $T_{amb} = 25\text{ °C}$.
- (3) $T_{amb} = -55\text{ °C}$.

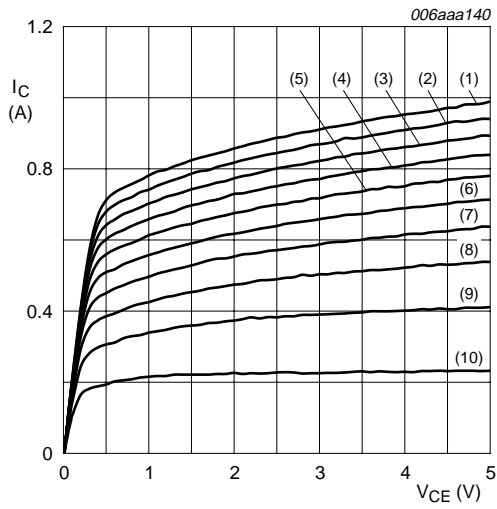
Fig 8. Selection -25: Collector-emitter saturation voltage as a function of collector current; typical values.



$I_C/I_B = 10$.

- (1) $T_{amb} = 150\text{ °C}$.
- (2) $T_{amb} = 25\text{ °C}$.
- (3) $T_{amb} = -55\text{ °C}$.

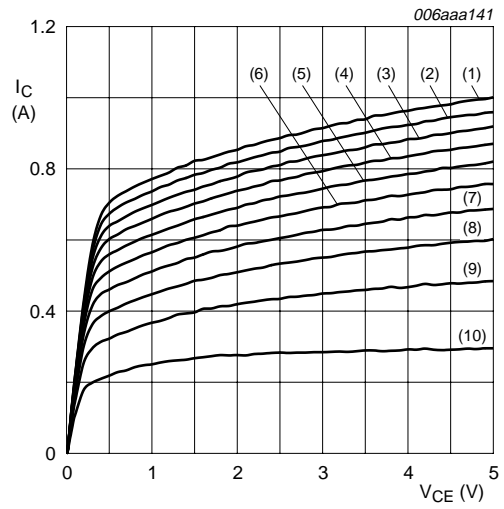
Fig 9. Selection -40: Collector-emitter saturation voltage as a function of collector current; typical values.



$T_{amb} = 25\text{ }^\circ\text{C}$.

- (1) $I_B = 16.0\text{ mA}$.
- (2) $I_B = 14.4\text{ mA}$.
- (3) $I_B = 12.8\text{ mA}$.
- (4) $I_B = 11.2\text{ mA}$.
- (5) $I_B = 9.6\text{ mA}$.
- (6) $I_B = 8.0\text{ mA}$.
- (7) $I_B = 6.4\text{ mA}$.
- (8) $I_B = 4.8\text{ mA}$.
- (9) $I_B = 3.2\text{ mA}$.
- (10) $I_B = 1.6\text{ mA}$.

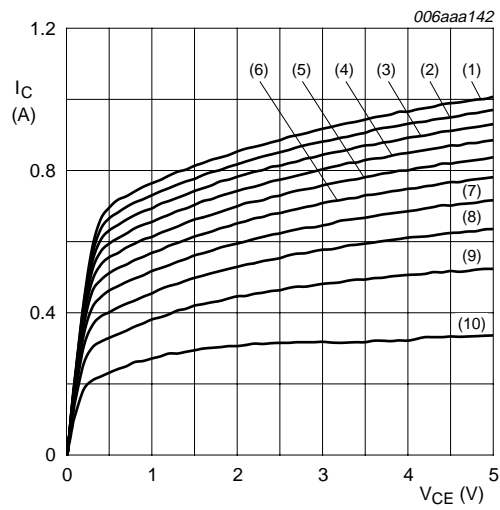
Fig 10. Selection -16: Collector current as a function of collector-emitter voltage; typical values.



$T_{amb} = 25\text{ }^\circ\text{C}$.

- (1) $I_B = 13.0\text{ mA}$.
- (2) $I_B = 11.7\text{ mA}$.
- (3) $I_B = 10.4\text{ mA}$.
- (4) $I_B = 9.1\text{ mA}$.
- (5) $I_B = 7.8\text{ mA}$.
- (6) $I_B = 6.5\text{ mA}$.
- (7) $I_B = 5.2\text{ mA}$.
- (8) $I_B = 3.9\text{ mA}$.
- (9) $I_B = 2.6\text{ mA}$.
- (10) $I_B = 1.3\text{ mA}$.

Fig 11. Selection -25: Collector current as a function of collector-emitter voltage; typical values.



$T_{amb} = 25\text{ }^{\circ}\text{C}$.

- (1) $I_B = 12.0\text{ mA}$.
- (2) $I_B = 10.8\text{ mA}$.
- (3) $I_B = 9.6\text{ mA}$.
- (4) $I_B = 8.4\text{ mA}$.
- (5) $I_B = 7.2\text{ mA}$.
- (6) $I_B = 6.0\text{ mA}$.
- (7) $I_B = 4.8\text{ mA}$.
- (8) $I_B = 3.6\text{ mA}$.
- (9) $I_B = 2.4\text{ mA}$.
- (10) $I_B = 1.2\text{ mA}$.

Fig 12. Selection -40: Collector current as a function of collector-emitter voltage; typical values.

8. Package outline

Plastic surface mounted package; 3 leads

SOT23

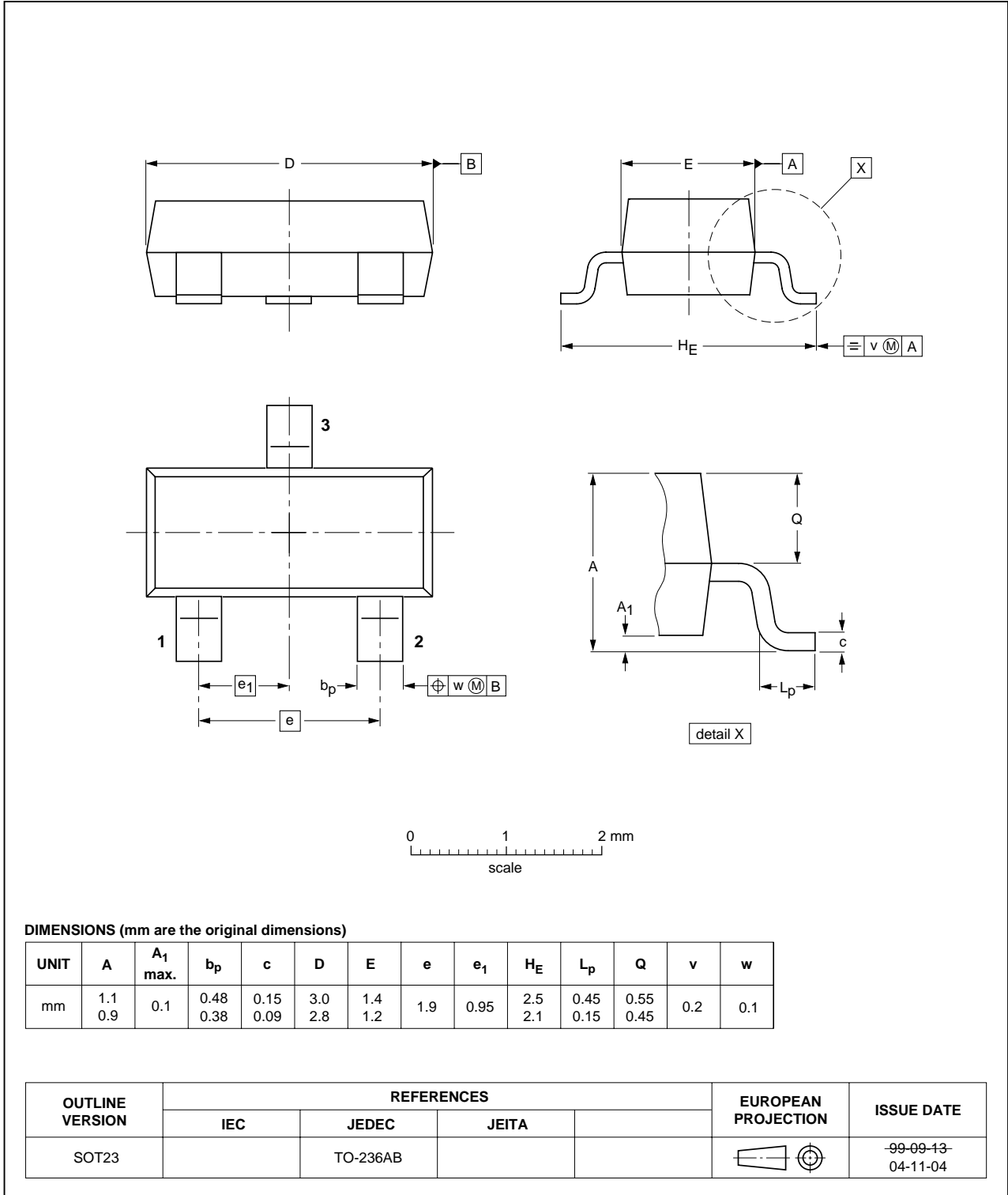


Fig 13. Package outline SOT23 (TO-236AB).

Plastic surface mounted package; 3 leads

SOT323

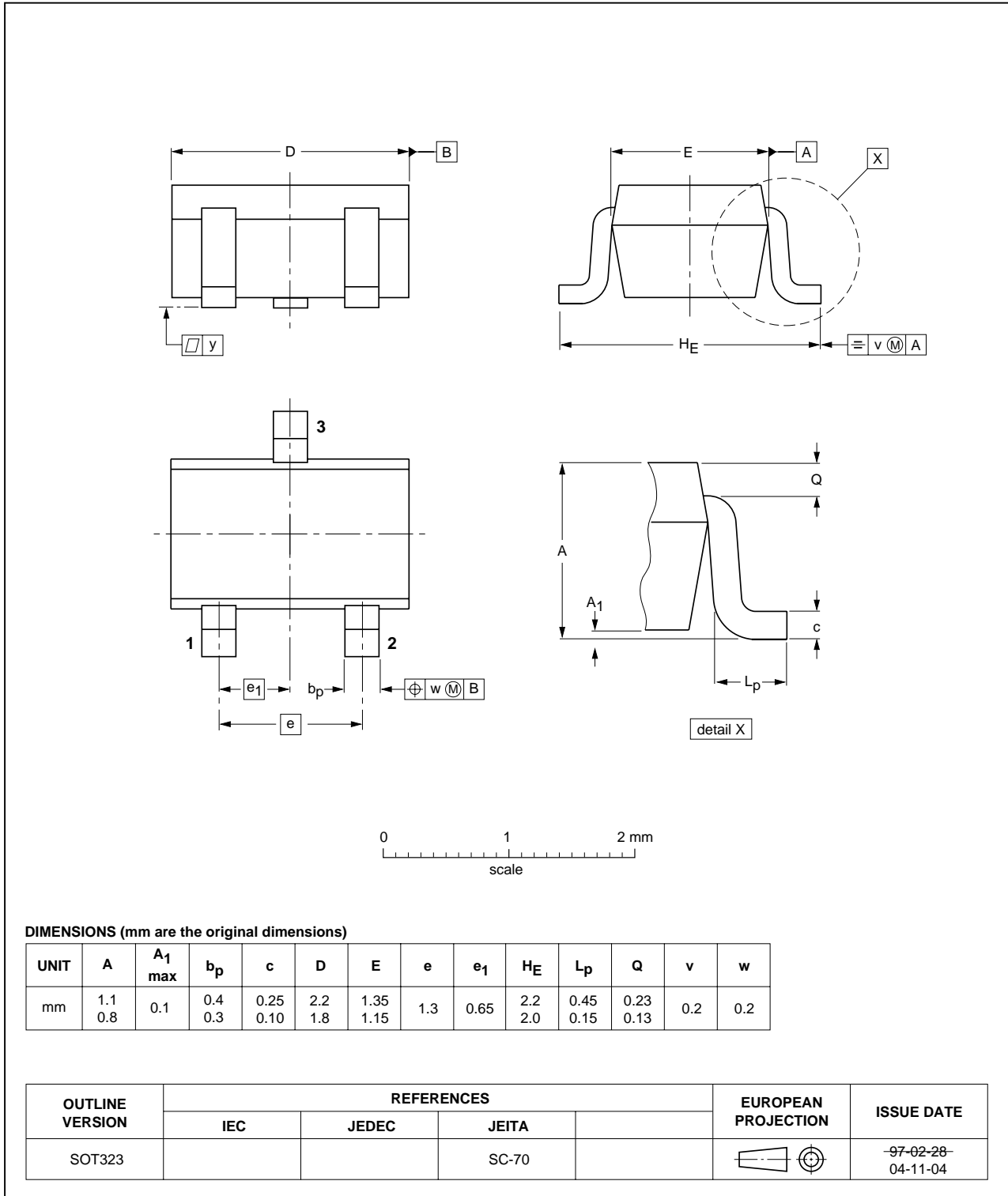


Fig 14. Package outline SOT323 (SC-70).

Plastic single-ended leaded (through hole) package; 3 leads

SOT54

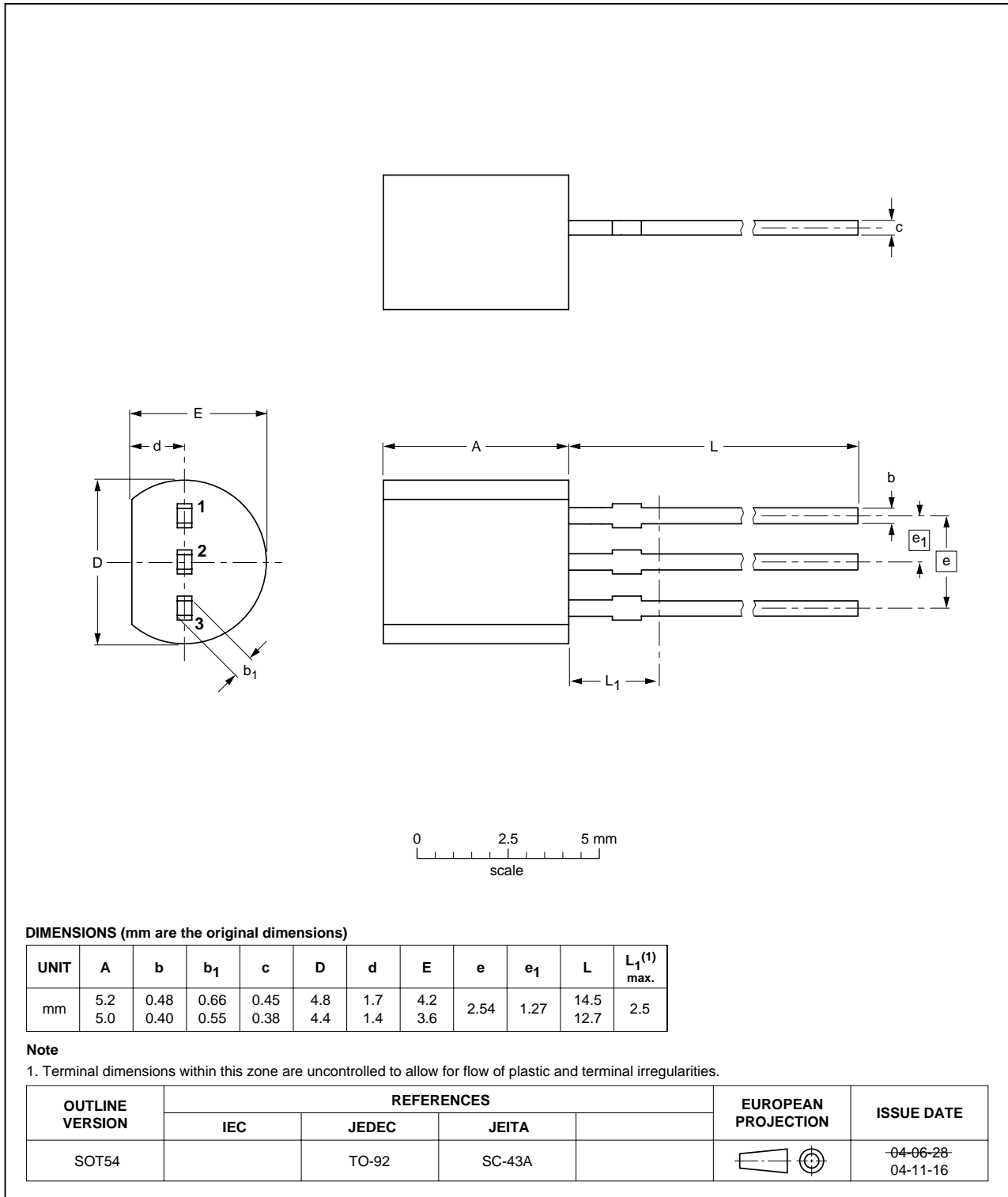


Fig 15. Package outline SOT54 (SC-43A/TO-92).

Plastic single-ended leaded (through hole) package; 3 leads (wide pitch) SOT54A

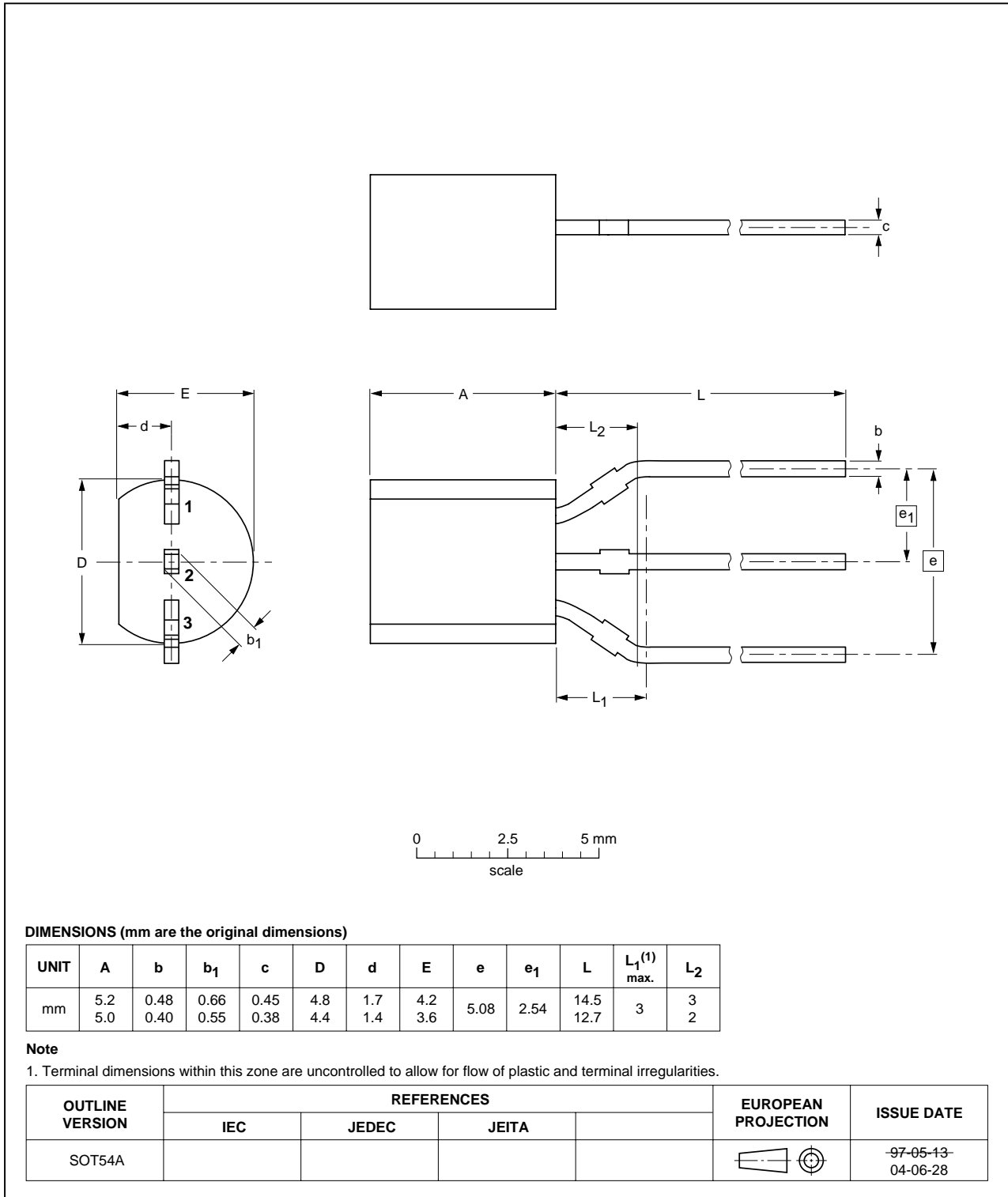


Fig 16. Package outline SOT54A.

Plastic single-ended leaded (through hole) package; 3 leads (on-circle)

SOT54 variant

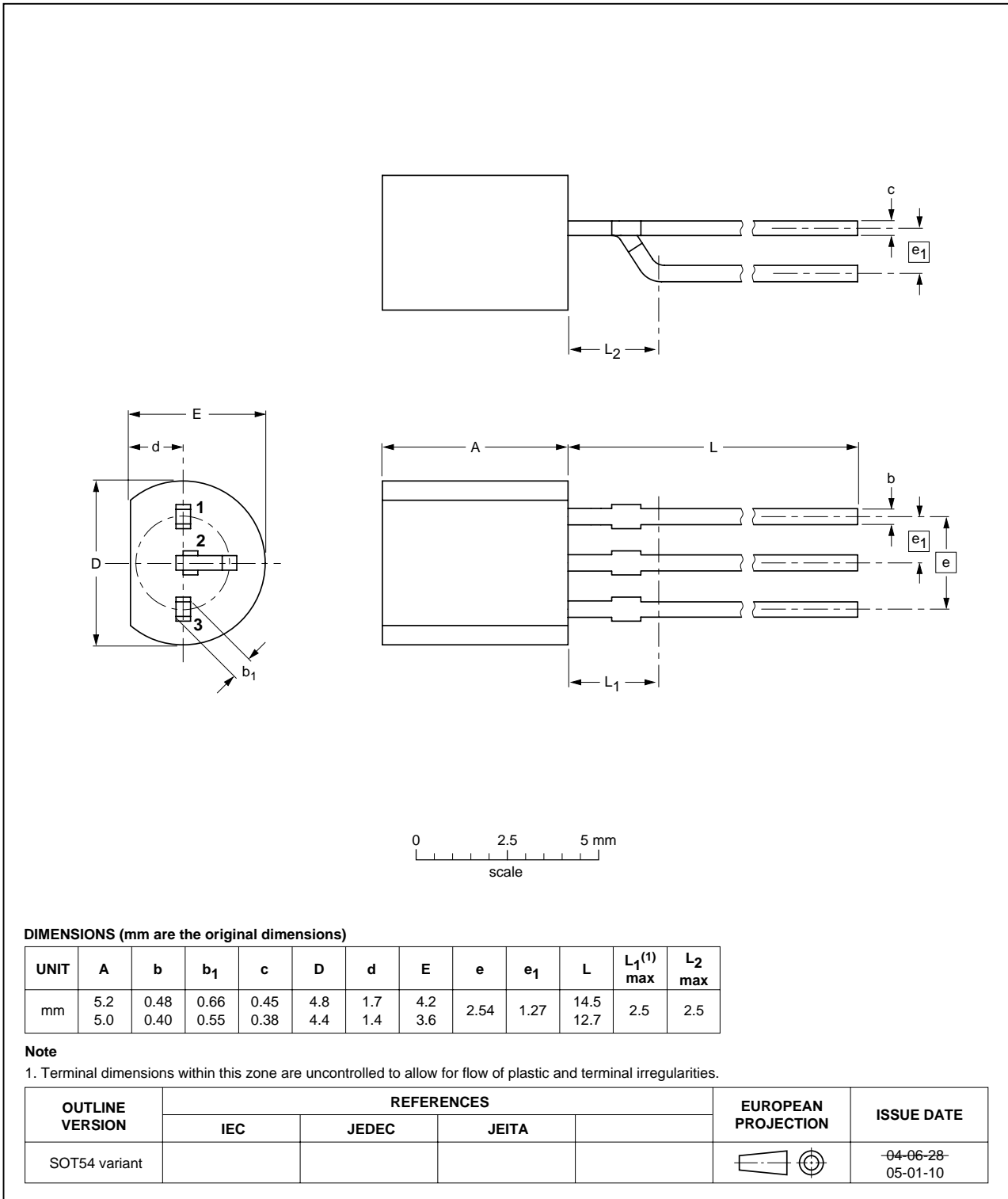


Fig 17. Package outline SOT54 variant.

9. Packing information

Table 9: Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code. [\[1\]](#)

| Type number | Package | Description | Packing quantity | | |
|-------------|----------------|---------------------------------|------------------|------|-------|
| | | | 3000 | 5000 | 10000 |
| BC817 | SOT23 | 4 mm pitch, 8 mm tape and reel | -215 | - | -235 |
| BC817W | SOT323 | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 |
| BC337 | SOT54 | bulk, straight leads | - | -412 | - |
| BC337 | SOT54A | tape and reel, wide pitch | - | - | -116 |
| BC337 | SOT54A | tape ammopack, wide pitch | - | - | -126 |
| BC337 | SOT 54 variant | bulk, delta pinning (on-circle) | - | -112 | - |

[1] For further information and the availability of packing methods, see [Section 14](#).

10. Revision history

Table 10: Revision history

| Document ID | Release date | Data sheet status | Change notice | Doc. number | Supersedes |
|--------------------------|--------------|-----------------------|-----------------|----------------|---|
| BC817_BC817W_ BC337_5 | 20050121 | Product data sheet | CPCN200302007F1 | 9397 750 14022 | BC817_4; BC817W_SER_4; BC337_3 |
| Modifications: | | | | | <ul style="list-style-type: none"> • The format of the data sheet has been redesigned to comply with the new presentation and information standard of Philips Semiconductors. • This data sheet is a combination of the previous data sheets BC817_4, BC817W_SER_4 and BC337_3. • Table 1 and 2 added • Table 3 Discrete pinning for SOT54A and SOT54 variant added • Table 5 Marking codes for BC337, BC337-16, BC337-25 and BC337-40 added • Table 8 Typical value for C_c changed to 3 pF according to CPCN200302007F1 • Figure 1, 2 and 3 amended • Figure 4, 5, 6, 7, 8, 9, 10, 11 and 12 added • Figure 15 changed according to CPCN200405006F • Figure 16 and 17 added • Section 9 added |
| BC817_4 | 20040105 | Product specification | - | 9397 750 12394 | BC817_3 |
| BC817W_SER_4 | 20040225 | Product specification | - | 9397 750 11944 | BC817W_SER_3 |
| BC337_3 | 19990415 | Product specification | - | 9397 750 05676 | BC337_338_CNV_2 |

11. Data sheet status

| Level | Data sheet status ^[1] | Product status ^{[2] [3]} | Definition |
|-------|----------------------------------|-----------------------------------|--|
| I | Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice. |
| II | Preliminary data | Qualification | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product. |
| III | Product data | Production | This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). |

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

12. Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

13. Disclaimers

Life support — These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

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14. Contact information

For additional information, please visit: <http://www.semiconductors.philips.com>

For sales office addresses, send an email to: sales.addresses@www.semiconductors.philips.com

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